



Supplementary

Amorphous Sb_2S_3 Nanospheres In-situ Grown on Carbon Nanotubes as Anodes for NIBs and KIBs

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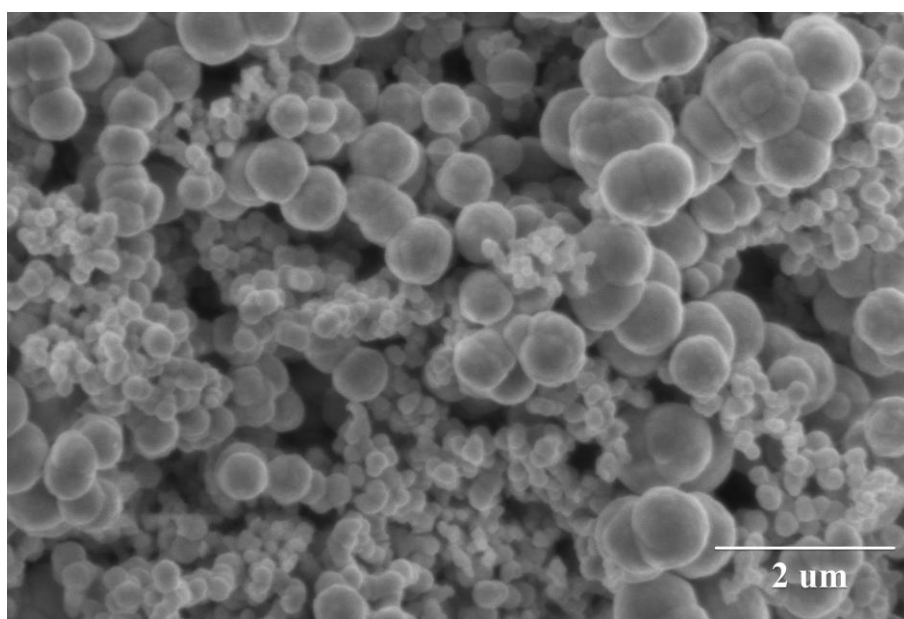


Figure S1. SEM image of pure Sb_2S_3 .

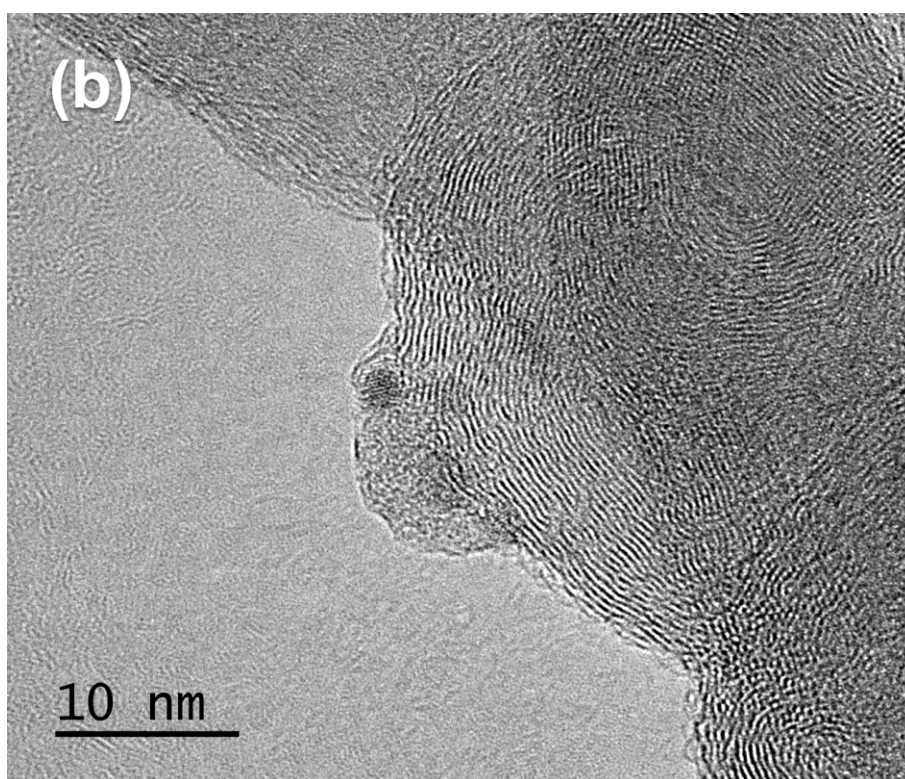
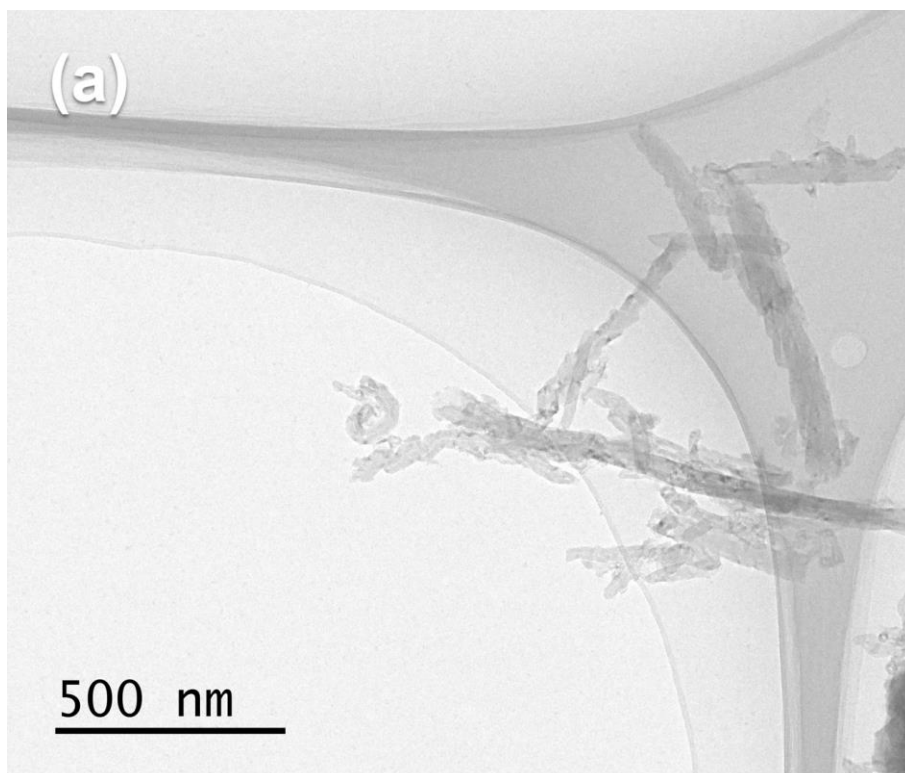


Figure S2. (a) TEM and (b) HRTEM images of the CNTs.

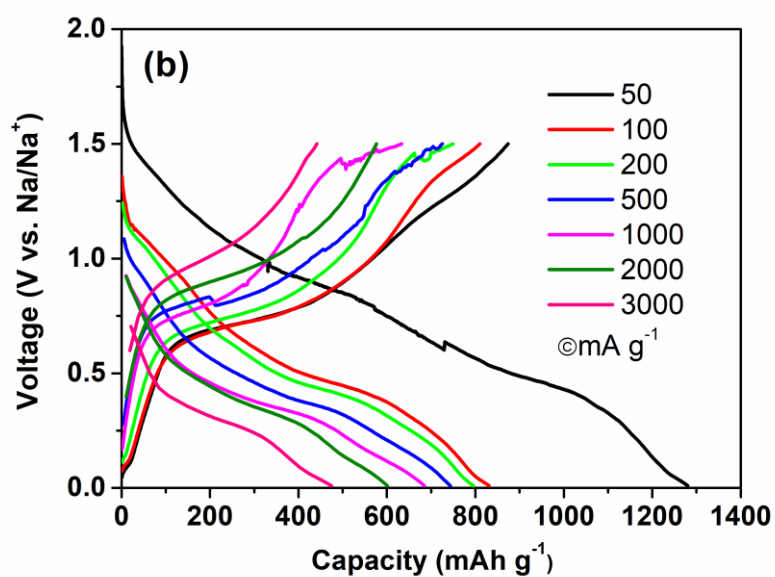
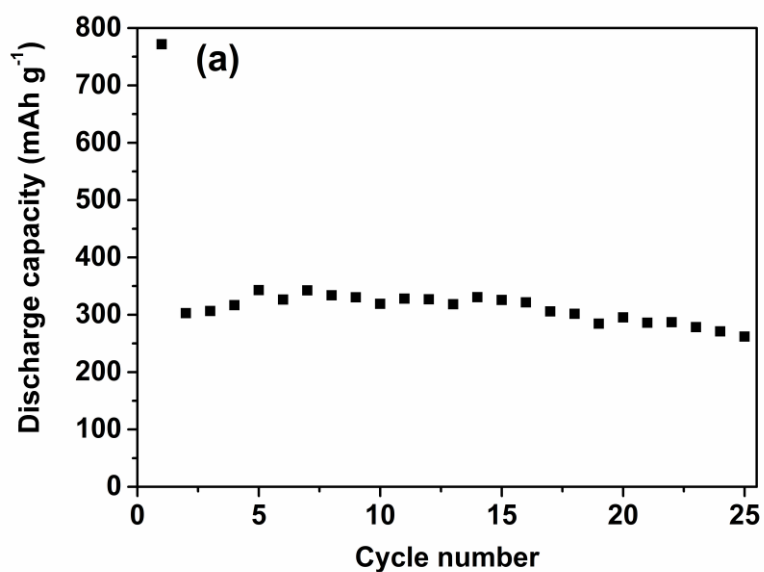
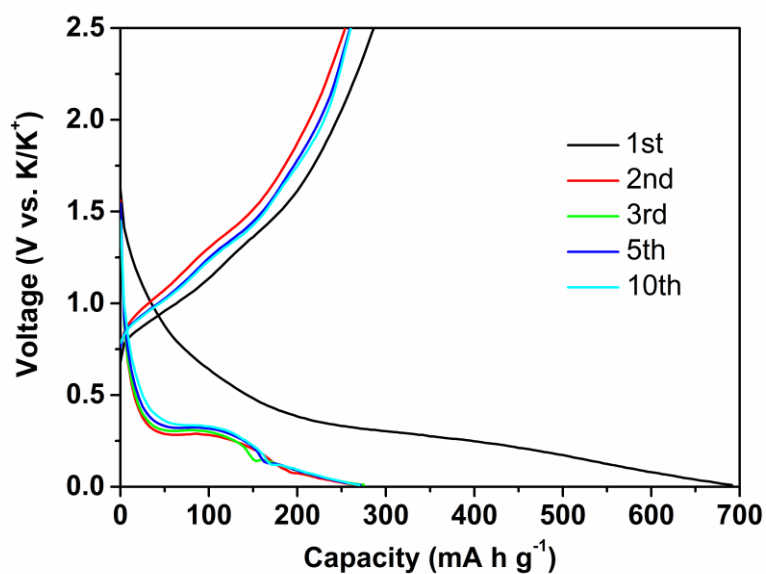


Figure S3. (a) Cycle performance of the Sb_2S_3 anode for NIBs at 100 mA g^{-1} . (b) Galvanostatic discharge-charge profiles of the $\text{Sb}_2\text{S}_3/\text{CNTs}$ anode for NIBs measured under various current densities.



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Figure S4. The galvanostatic discharge/charge curves of the Sb₂S₃/CNTs anode for KIBs at 500 mA g⁻¹.